

长春新产业光电技术有限公司

Changchun New Industries Optoelectronics Tech, Co., Ltd.

DATA SHEET

EO-1064-Subnano-Hi/1~4000µJ/1~20W

HIGH ENERGY DIODE PUMPED ALL-SOLID-STATE Q-SWITCHED LASER

High energy diode pumped all solid state Q-switched laser at 1064nm has the features of high single pulse energy, short pulse duration, and high peak power, which is widely used in LIBS, Scanning imaging radar, OPO, laser ranging and so on.



| Wavelength (nm) | 1064±1nm | |
|------------------------------------|--------------------------------------|--------------|
| Operating mode | Q-switched: EO (Electro-optic) | |
| Single pulse energy (uJ) | 2000uJ@5KHz | 4000uJ@5KHz |
| Output power (W) | 10 | 20 |
| Power stability | <5%, <3%, <2% | |
| Pulse duration (ns) | <1.5ns@5KHz | 1.5~2ns@5KHz |
| Rep. rate (kHz) | 100Hz~10kHz (Customized) | |
| Beam diameter (mm) | ~2mm | ~2.5mm |
| Beam divergence, full angle (mrad) | <3mrad | |
| Cooled method | Air cooled@<2kHz; Water cooled@>2kHz | |
| Warm-up time (minutes) | <15 | |
| Power supply | DC 24V | |
| Operating temperature (°C) | 15~30 | |
| Expected lifetime (hours) | 10000h | |
| Warranty period | 1 year | |





